High Voltage Transistor

PNP Silicon

Features

• Pb-Free Packages are Available



Rating	Symbol	Value	Unit
Collector - Emitter Voltage	V_{CEO}	-150	Vdc
Collector - Base Voltage	V_{CBO}	-160	Vdc
Emitter-Base Voltage	V_{EBO}	-5.0	Vdc
Collector Current – Continuous	Ic	-500	mAdc

Maximum ratings are those values beyond which device damage can occur. Maximum ratings applied to the device are individual stress limit values (not normal operating conditions) and are not valid simultaneously. If these limits are exceeded, device functional operation is not implied, damage may occur and reliability may be affected.

THERMAL CHARACTERISTICS

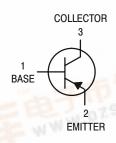
Characteristic	Symbol Max		Unit	
Total Device Dissipation FR-5 Board (Note 1) T _A = 25°C	P _D	225	mW	
Derate Above 25°C		1.8	mW/°C	
Thermal Resistance, Junction-to-Ambient	$R_{\theta JA}$	556	°C/W	
Total Device Dissipation Alumina Substrate (Note 2) T _A = 25°C Derate Above 25°C	P _D	300	mW mW/°C	
Derate Above 25°C		2.4	mvv/°C	
Thermal Resistance, Junction-to-Ambient	$R_{\theta JA}$	417	°C/W	
Junction and Storage Temperature	T _J , T _{stg}	-55 to +150	°C	

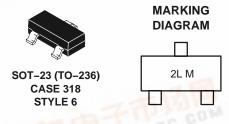
- 1. $FR-5 = 1.0 \times 0.75 \times 0.062$ in.
- 2. Alumina = $0.4 \times 0.3 \times 0.024$ in 99.5% alumina.



ON Semiconductor®

http://onsemi.com





2L = Device Code M = Month Code

ORDERING INFORMATION

Device	Package	Shipping [†]
MMBT5401LT1	SOT-23	3000 Tape & Reel
MMBT5401LT1G	SOT-23 (Pb-Free)	3000 Tape & Reel
MMBT5401LT3	SOT-23	10,000 Tape & Reel
MMBT5401LT3G	SOT-23 (Pb-Free)	10,000 Tape & Reel

†For information on tape and reel specifications, including part orientation and tape sizes, please refer to our Tape and Reel Packaging Specifications Brochure, BRD8011/D.

Preferred devices are recommended choices for future use and best overall value.



ELECTRICAL CHARACTERISTICS (T_A = 25°C unless otherwise noted)

Characteristic	Symbol	Min	Max	Unit
OFF CHARACTERISTICS				
Collector – Emitter Breakdown Voltage $(I_C = -1.0 \text{ mAdc}, I_B = 0)$	V _(BR) CEO	-150	-	Vdc
Collector – Base Breakdown Voltage $(I_C = -100 \mu Adc, I_E = 0)$	V _(BR) CBO	-160	-	Vdc
Emitter – Base Breakdown Voltage ($I_E = -10 \mu Adc$, $I_C = 0$)	V _{(BR)EBO}	-5.0	_	Vdc
Collector Cutoff Current $(V_{CB} = -120 \text{ Vdc}, I_E = 0)$ $(V_{CB} = -120 \text{ Vdc}, I_E = 0, T_A = 100^{\circ}\text{C})$	I _{CES}	- -	-50 -50	nAdc μAdc
ON CHARACTERISTICS				
DC Current Gain $ \begin{aligned} &(I_C = -1.0 \text{ mAdc, } V_{CE} = -5.0 \text{ Vdc)} \\ &(I_C = -10 \text{ mAdc, } V_{CE} = -5.0 \text{ Vdc)} \\ &(I_C = -50 \text{ mAdc, } V_{CE} = -5.0 \text{ Vdc)} \end{aligned} $	h _{FE}	50 60 50	- 240 -	_
Collector – Emitter Saturation Voltage ($I_C = -10$ mAdc, $I_B = -1.0$ mAdc) ($I_C = -50$ mAdc, $I_B = -5.0$ mAdc)	V _{CE(sat)}	_ _	-0.2 -0.5	Vdc
Base – Emitter Saturation Voltage ($I_C = -10$ mAdc, $I_B = -1.0$ mAdc) ($I_C = -50$ mAdc, $I_B = -5.0$ mAdc)	V _{BE(sat)}	_ _	-1.0 -1.0	Vdc
SMALL-SIGNAL CHARACTERISTICS				
Current – Gain — Bandwidth Product $(I_C = -10 \text{ mAdc}, V_{CE} = -10 \text{ Vdc}, f = 100 \text{ MHz})$	fT	100	300	MHz
Output Capacitance $(V_{CB} = -10 \text{ Vdc}, I_E = 0, f = 1.0 \text{ MHz})$	C _{obo}	-	6.0	pF
Small Signal Current Gain ($I_C = -1.0 \text{ mAdc}$, $V_{CE} = -10 \text{ Vdc}$, $f = 1.0 \text{ kHz}$)	h _{fe}	40	200	-
Noise Figure (I _C = $-200 \mu Adc$, V _{CE} = $-5.0 Vdc$, R _S = 10Ω , f = $1.0 kHz$)	NF	_	8.0	dB

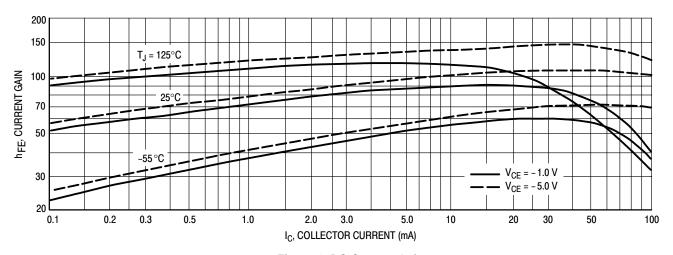


Figure 1. DC Current Gain

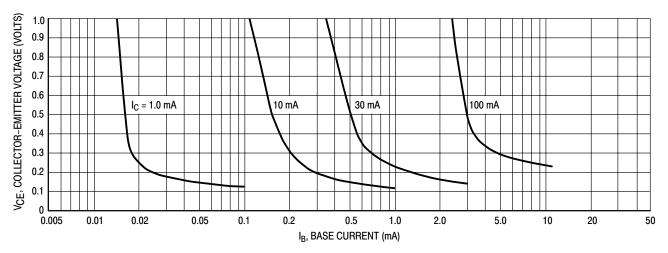


Figure 2. Collector Saturation Region

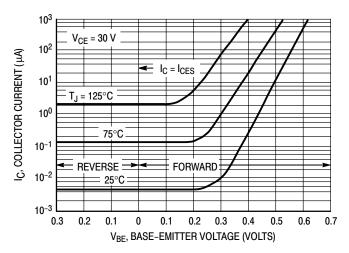


Figure 3. Collector Cut-Off Region

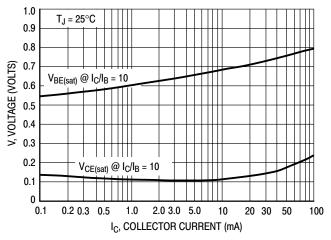


Figure 4. "On" Voltages

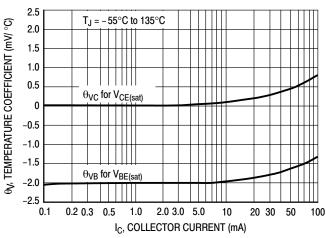
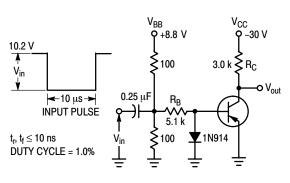


Figure 5. Temperature Coefficients



Values Shown are for I_C @ 10 mA

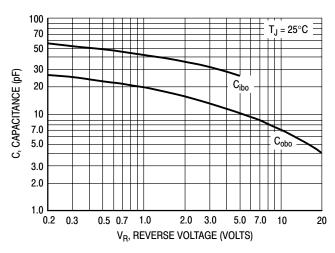


Figure 7. Capacitances

Figure 6. Switching Time Test Circuit

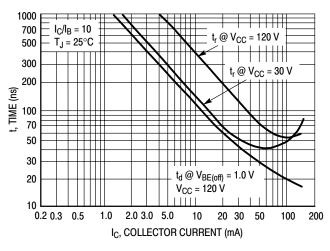


Figure 8. Turn-On Time

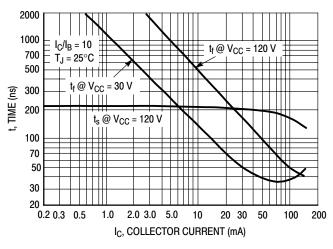
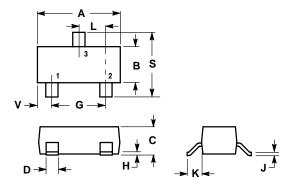


Figure 9. Turn-Off Time

PACKAGE DIMENSIONS

SOT-23-3 (TO-236) CASE 318-08 **ISSUE AK**



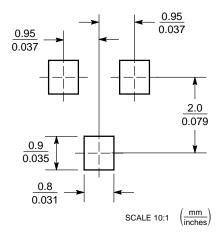
- NOTES:
 1. DIMENSIONING AND TOLERANCING PER ANSI Y14.5M, 1982.
 2. CONTROLLING DIMENSION: INCH.
 3. MAXIMUM LEAD THICKNESS INCLUDES LEAD FINISH THICKNESS. MINIMUM LEAD THICKNESS IS THE MINIMUM THICKNESS OF PAGE MATERIAL.
- BASE MATERIAL. 318-01 THRU -07 AND -09 OBSOLETE, NEW STANDARD 318-08.

	INCHES		MILLIM	IETERS
DIM	MIN	MAX	MIN	MAX
Α	0.1102	0.1197	2.80	3.04
В	0.0472	0.0551	1.20	1.40
С	0.0350	0.0440	0.89	1.11
D	0.0150	0.0200	0.37	0.50
G	0.0701	0.0807	1.78	2.04
Н	0.0005	0.0040	0.013	0.100
J	0.0034	0.0070	0.085	0.177
K	0.0140	0.0285	0.35	0.69
L	0.0350	0.0401	0.89	1.02
S	0.0830	0.1039	2.10	2.64
V	0.0177	0.0236	0.45	0.60

STYLE 6:
PIN 1. BASE
2. EMITTER
3. COLLECTO

COLLECTOR

SOLDERING FOOTPRINT*



^{*}For additional information on our Pb-Free strategy and soldering details, please download the ON Semiconductor Soldering and Mounting Techniques Reference Manual, SOLDERRM/D.

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